

Low Capacitance TVS Diode

- ESD / transient protection of high-speed data lines in 3.3 / 5 / 12 V applications according to: IEC61000-4-2 (ESD): up to ± 25 KV (contact) IEC61000-4-4 (EFT): 40 A (5/50 ns) IEC61000-4-5 (surge): up to 2.5 A (8/20 μs)
- Smallest form factor down to 1.0 x 0.6 x 0.4 mm
- Max. working voltage: -8 / +14 V or +8 / -14 V
- \bullet Ultra low dynamic resistance down to $\textbf{0.3}~\Omega$
- Very low capacitance down to 2 pF
- Very low reverse current < 1 nA typ.
- Very low series inductance down to 0.4 nH
- Pb-free (RoHS compliant) package

Applications

- USB 2.0, 10/100 Ethernet, Firewire, DVI
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and destop computers, peripherals



ESD8V0L1B-02EL ESD8V0L1B-02LRH ESD8V0L2B-03L



3	1
3	2

Туре	Package	Configuration	Marking
ESD8V0L1B-02EL	TSLP-2-18	1 channel, bi-directional	E7
ESD8V0L1B-02LRH	TSLP-2-17	1 channel, bi-directional	B3
ESD8V0L2B-03L	TSLP-3-1	2 channels, bi-directional	B3





Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD contact discharge ¹⁾	V _{ESD}		kV
ESD8V0L1B		25	
ESD8V0L2B, between all pins		15	
Peak pulse current ($t_p = 8 / 20 \ \mu s$) ²⁾	I _{pp}		A
ESD8V0L1B		2.5	
ESD8V0L2B		1	
Operating temperature range	T _{op}	-55125	°C
Storage temperature	T _{stg}	-65150	

 $^{1}V_{\text{ESD}}$ according to IEC61000-4-2

 $^{2}I_{pp}$ according to IEC61000-4-5



Parameter	Symbol	Values			Unit
		min.	typ.	max.	1
Characteristics	•				•
Reverse working voltage	V _{RWM}	-8	-	14	V
Breakdown voltage	V _(BR)				
<i>I</i> _(BR) = 1 mA, from pin 2 to 1, ESD8V0L1B		14.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 1 to 2, ESD8V0L1B		8.5	-	-	
<i>I</i> _(BR) = 1 mA, from pin 1/2 to 3, ESD8V0L2B		14.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 3 to 1/2, ESD8V0L2B		8.5	-	-	
$I_{(BR)}$ = 1 mA, from pin 1 to 2, ESD8V0L2B		23	-	-	
Reverse current	I _R	-	< 1	50	nA
V_{R} = 3 V, between all pins					
Clamping voltage (contact) ¹⁾	V _{CL}				V
V_{ESD} = +15 kV , from pin 1 to 2, ESD8V0L1B		-	21	-	
V_{ESD} = -15 kV, from pin 1 to 2, ESD8V0L1B		-	16	-	
V_{ESD} = +15 kV , from pin 1/2 to 3, ESD8V0L2B		-	26	-	
V_{ESD} = -15 kV , from pin 1/2 to 3, ESD8V0L2B		-	20	-	
Line capacitance ²⁾	CT				pF
V _R = 0 V, <i>f</i> = 1 MHz, ESD8V0L1B		-	8.5	13	
V _R = 0 V, <i>f</i> = 1 MHz, ESD8V0L2B,					
from pin 1/2 to 3		-	4	7	
from pin 1 to 2, pin 3 is not connected		-	2	4	
Dynamic resistance (tp=30ns)	R _D				Ω
ESD8V0L1B		-	0.3	-	
ESD8V0L2B		-	0.6	-	

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

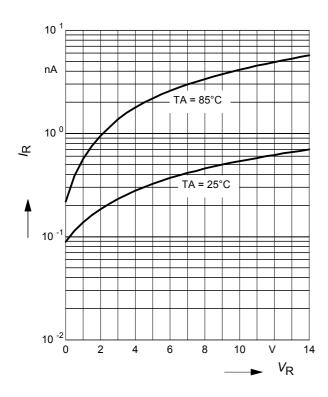
 $^{1}V_{\text{ESD}}$ according to IEC61000-4-2

²Total capacitance line to ground



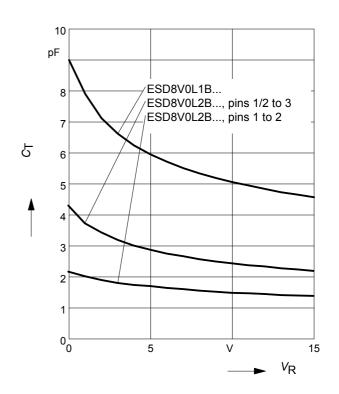
Reverse current $I_{R} = f(V_{R})$

 T_A = Parameter



Diode capacitance $C_{T} = f(V_{R})$

f = 1MHz

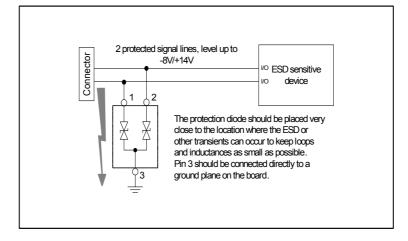






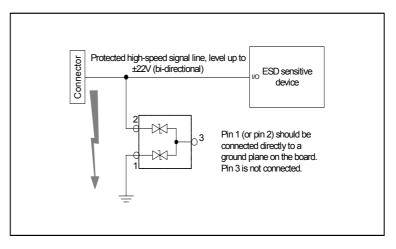
Application example ESD8V0L2B...

2 channels, bi-directional



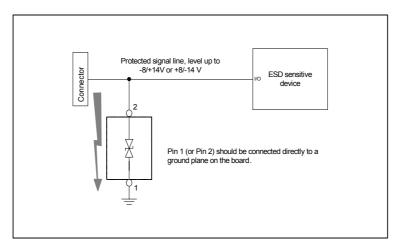
Application example ESD8V0L2B...

1 high-speed channel, bi-directional

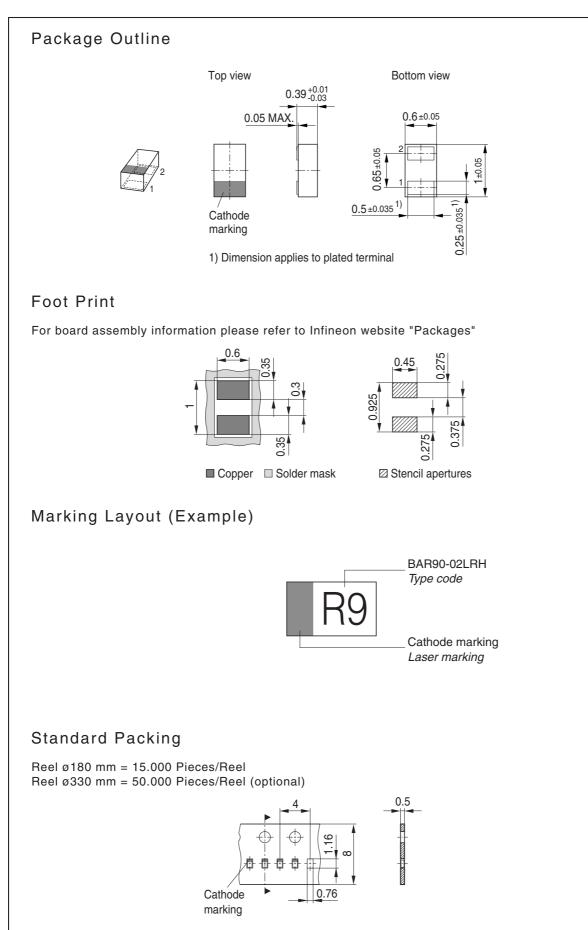


Application example ESD8V0L1B...

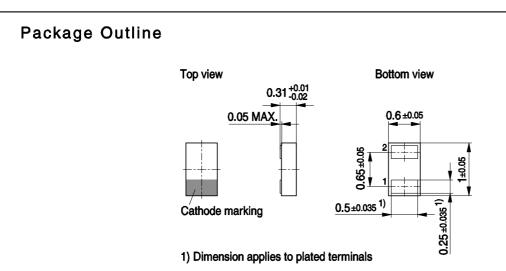
1 channel, bi-directional





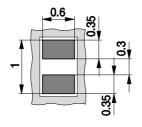


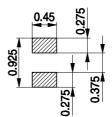




Foot Print

For board assembly information please refer to Infineon website "Packages"

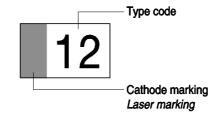




Copper Solder mask

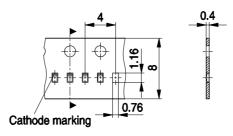
 $\ensuremath{\boxtimes}$ Stencil apertures

Marking Layout



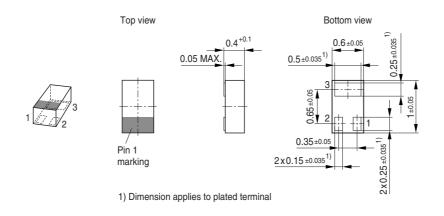
Standard Packing

Reel ø330 mm = 15.000 Pieces/Reel



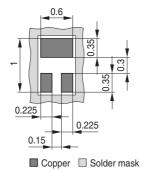


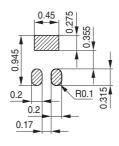




Foot Print

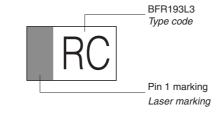
For board assembly information please refer to Infineon website "Packages"





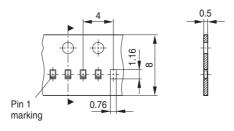
Stencil apertures

Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel







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